RECTRON
SEMICONDUCTOR
TECHNICAL SPECIFICATION

HVP5
THRU
HVP16

HIGH VOLTAGE ASSEMBLIED RECTIFIER

VOLTAGE RANGE 5000 to 16000 Volts CURRENT 0.75 Amperes

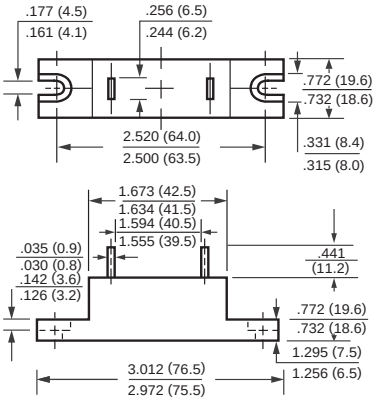
FEATURES

* Low cost
* Low leakage
* Isolated case
* Surge overload rating - 50 amperes peak
* Mounting position: Any
* Low forward voltage drop

MECHANICAL DATA

* Epoxy: Device has UL flammability classification 94V-O

HVP



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

MAXIMUM RATINGS (At T_A = 25°C unless otherwise noted)

RATINGS	SYMBOL	HVP5	HVP8	HVP10	HVP12	HVP14	HVP15	HVP16	UNITS
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	5	8	10	12	14	15	16	K Volts
Maximum RMS Voltage	V_{RMS}	3.5	5.6	7.0	8.4	9.8	10.5	11.2	K Volts
Maximum DC Blocking Voltage	V_{DC}	5	8	10	12	14	15	16	K Volts
Maximum Average Forward Rectified Current at T_A = 50°C	I_O	750							mAmps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	50							Amps
Operating and Storage Temperature Range	T_J,T_{STG}	-20 to + 135							°C

ELECTRICAL CHARACTERISTICS (At T_A = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	HVP5	HVP8	HVP10	HVP12	HVP14	HVP15	HVP16	UNITS
Maximum Instantaneous Forward Voltage at 0.35A DC	V_F	8.0	14.0						Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage	I_R	5.0							uAmps

NOTES: Enough heat sink must be considered in application.

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RATING AND CHARACTERISTIC CURVES (HVP5 THRU HVP16)

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

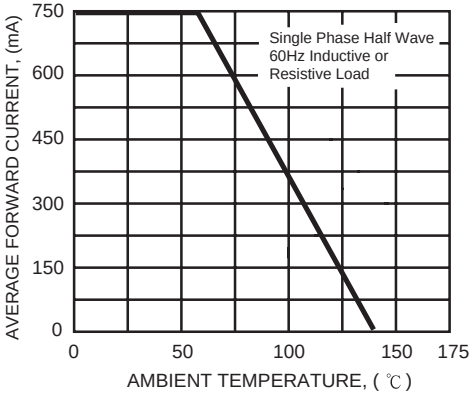

FIG. 2 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

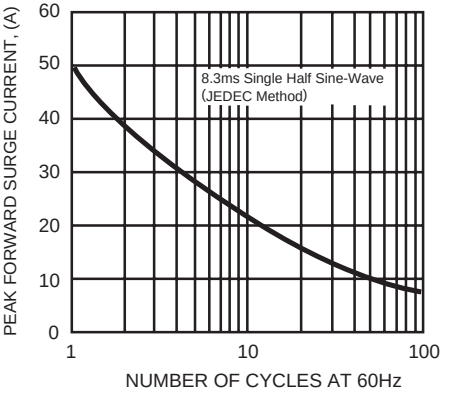

FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

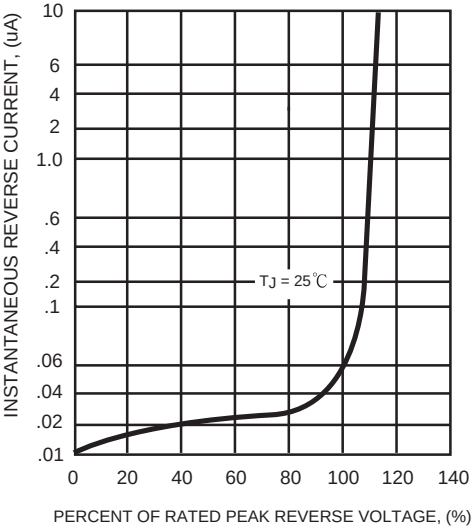

FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS